

2SJ358C

P-CHANNEL MOSFET FOR SWITCHING

R07DS1262EJ0300 Rev.3.00 Aug 17, 2015

Description

The 2SJ358C, P-channel vertical type MOSFET designed for general-purpose switch, is a device which can be driven directly by a 4.0 V power source.

Features

• Directly driven by a 4.0 V power source.

• Low on-state resistance

RDS(on)1 = 143 m Ω MAX. (VGS = -10 V, ID = -2.0 A)

RDS(on)2 = 179 m Ω MAX. (Vgs = -4.5 V, ID = -2.0 A)

RDS(on)3 = 190 m Ω MAX. (VGS = -4.0 V, ID = -2.0 A)

Ordering Information

Part Number	Lead Plating	Packing	Package	
2SJ358C-T1-AZ/AY	-AZ : Sn-Bi , -AY : Pure Sn	1000p/Reel	SC-84 (MP-2)	

Remark "-AZ/AY" indicates Pb-free. This product does not contain Pb in external electrode and other parts.

Marking XT1

Absolute Maximum Ratings (TA = 25°C)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDS = 0 V)	Vgss	∓20	V
Drain Current (DC)	I _{D(DC)}	∓3.5	Α
Drain Current (pulse) Note1	I _{D(pulse)}	∓14	Α
Total Power Dissipation Note2	Рт	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	T _{stg}	-55 to +150	°C

Note1 PW \leq 10 μ s, Duty Cycle \leq 1%

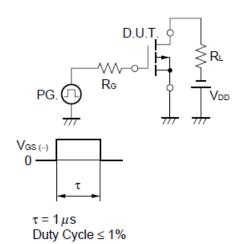
Note2 16 cm² X 0.7mm, ceramic substrate used

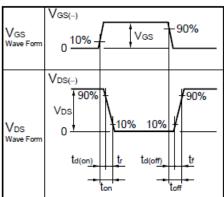
Electrical Characteristics (T_A = 25°C)

Characteristics	Symbol	Test Conditions	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	IDSS	V _{DS} = -60 V, V _{GS} = 0 V			-1.0	μА
Gate Leakage Current	Igss	$V_{GS} = \mp 20 \text{ V}, V_{DS} = 0 \text{ V}$			∓10	μА
Gate to Source Cut-off Voltage	V _{GS(off)}	V _{DS} = -10V, I _D = -1 mA	-1.5	-1.9	-2.5	V
Forward Transfer Admittance Note	y _{fs}	V _{DS} = -10 V, I _D = -2.0 A	3.0	6.2		S
Drain to Source On-state Resistance Note	R _{DS(on)1}	V _G S = -10 V, I _D = -2.0 A		114	143	mΩ
	R _{DS(on)2}	V _G S = -4.5 V, I _D = -2.0 A		134	179	mΩ
	RDS(on)3	Vgs = -4.0 V, ID = -2.0 A		142	190	mΩ
Input Capacitance	Ciss	V _{DS} = -10 V,		666		рF
Output Capacitance	Coss	$V_{GS} = 0 V$,		120		рF
Reverse Transfer Capacitance	Crss	f = 1.0 MHz		58		рF
Turn-on Delay Time	td(on)	$V_{DD} = -30 \text{ V},$		12		ns
Rise Time	tr	ID = -2 A,		5		ns
Turn-off Delay Time	td(off)	V _G S = -10 V,		58		ns
Fall Time	t _f	$R_G = 10 \Omega$		27		ns
Total Gate Charge	Q G	ID = -3.5 A, VDD = -48 V, VGS = -10 V		12		nC
Body Diode Forward Voltage Note	V _{F(S-D)}	IF = 3.5 A, VGS = 0 V		0.87		٧

Note Pulsed

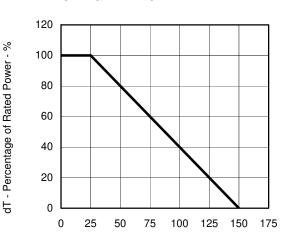
Test Circuit Switching Time





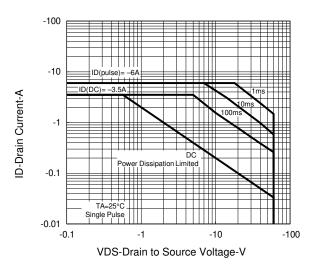
Typical Characteristics (T_A = 25°C)

DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA

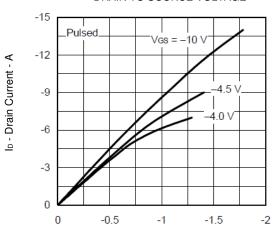


T_A - Ambient Temperature - °C

FORWARD BIAS SAFE OPERATING AREA

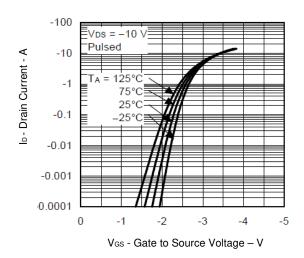


DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE

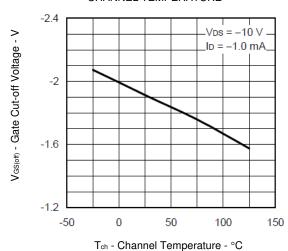


VDS - Drain to Source Voltage - V

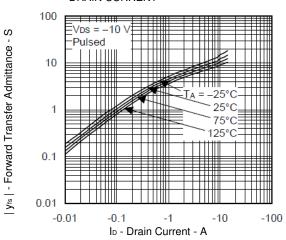
FORWARD TRANSFER CHARACTERISTICS



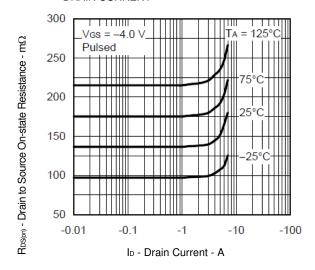
GATE CUT-OFF VOLTAGE vs. CHANNEL TEMPERATURE



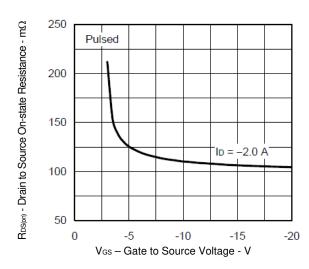
FORWARD TRANSFER ADMITTANCE vs. DRAIN CURRENT



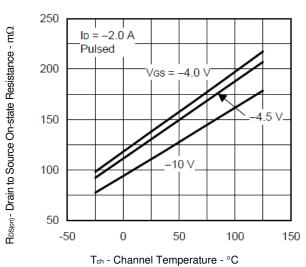
DRAIN TO SOURCE ON-STATE RESISTANCE vs. DRAIN CURRENT



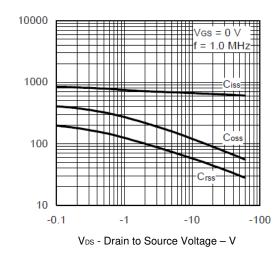
DRAIN TO SOURCE ON-STATE RESISTANCE vs. GATE TO SOURCE VOLTAGE



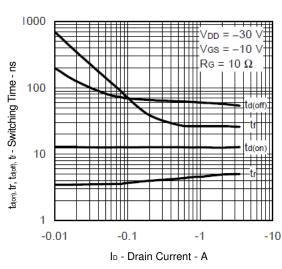
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



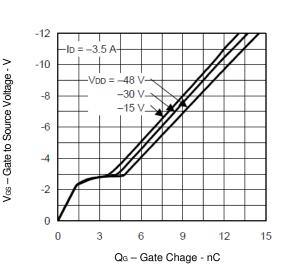
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



SWITCHING CHARACTERISTICS

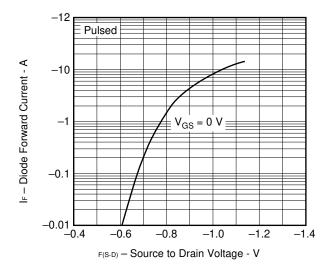


DYNAMIC INPUT CHARACTERISTICS



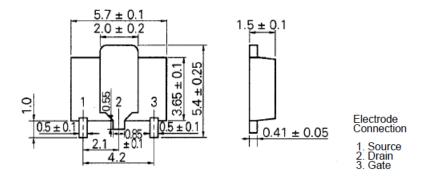
Ciss, coss, crss - Capacitance - pF

SOURCE TO DRAIN DIODE FORWARD VOLTAGE

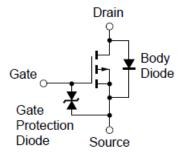


Package Drawings (Unit: mm)

SC-84 (MP-2)



Equivalent Circuit



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

2SJ358C

		Description		
Rev.	Date	Page	Summary	
1.00	Sep , 2013	-	First Edition Issued	
1.10	Nov , 2013	2	Test Circuit	
2.00	Jun, 2015	3	Added FORWARD BIAS SAFE OPERATING AREA	
3.00	Aug , 2015	3	Changed FORWARD BIAS SAFE OPERATING AREA	
		5	Changed SOURCE TO DRAIN DIODE FORWARD VOLTAGE	

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